

Origin and consequences of the moiré stripe formation on the surface of Bi₂Se₃ topological insulator thin films and nanobelts

Matteo Salvato^a, Maurizio De Crescenzi^a, Paola Castrucci^a, Simona Boninelli^b, Annica Black-Schaffer^c, Floriana Lombardi^d

^a*Dipartimento di Fisica and INFN Università degli Studi di Roma "Tor Vergata" Via della Ricerca Scientifica 1, 00133 Roma, Italy*

^b*CNR-IMM, 95121 Catania, Italy*

^c*Department of Physics and Astronomy, Uppsala University, 75120 Uppsala, Sweden*

^d*Quantum Device Physics Laboratory, Department of Microtechnology and Nanoscience, Chalmers University of Technology, 41296 Goteborg, Sweden*

Corresponding author email: matteo.salvato@roma2.infn.it

Moiré patterns are generated in low dimensional materials in presence of a lattice mismatch or a twist angle between two adjacent layers. Such structural deformation gives rise to a new scale of periodicity on the material surface which leads to challenging phenomena both from theoretical and experimental point of view. Topological insulators are a new class of materials where surface states play a fundamental role on their physical properties. Because of the quantum spin Hall effect, this material presents Dirac surface states and bulk bandgap for thickness higher than 6 nm and the interesting characteristic of helicity of the surface states which locks the electron spin with the momentum direction. Therefore, the formation of moiré stripes on the surface of Topological Insulators leads by itself to unpredictable consequences on important parameters as surface electron Fermi velocity and Dirac cone formation. Moiré patterns are observed in several Topological Insulators and their origin is ascribed to the mismatch between film and substrate lattice. Here we present experimental results, which show moiré stripes on the surface of Topological Insulator Bi₂Se₃, both in form of thin films and nanobelts, which cannot be ascribed to the presence of a substrate but induced by the growth mechanism. The experimental data, supported by calculations based on Density Functional Theory, show the interesting properties of the modulation of the electrical conductivity along the stripes, a result that anticipates a possible new application of this material in field as twistrionics and stripetronics.